Structure and "Oxidation Behavior" of $W_{24}O_{70}$, a New Member of the {103} *CS* Series of Tungsten Oxides

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Reduced tungsten trioxide crystals WO_{3-r} , formed by vapor transport from a preparation with bulk composition $WO_{-2.90}$, have been studied by X-ray diffraction and electron microscopy. A single-crystal X-ray investigation showed the existence of the ordered {103} CS-structure $W_{24}O_{70}$, a new member of the homologous series W_nO_{3n-2} . Electron diffraction patterns of crystal fragments, with a few exceptions, showed the presence of the $W_{24}O_{70}$ phase (composition $WO_{2.917}$). Lattice images, however, indicated a fairly ordered {103} CS-phase, $W_{24}O_{70}$, intergrown with slabs of WO_3 giving gross compositions of the examined crystals in the range $WO_{2.93}$ - $WO_{2.96}$. The wide WO_3 slabs were probably formed by an oxidation process during the preparation.

Introduction

In 1953, Magnéli introduced the concept "homologous series" (1) to denote slightly reduced structures of the ReO₃ type which "recurrent dislocations contained of atoms" along parallel planes, later called crystallographic shear (CS)-planes (2). At that time, $W_{20}O_{58}$ (3) was the only known member of the series Me_nO_{3n-2} . Figure 1 illustrates the structure of W₂₀O₅₈. The CSplanes run in the [301] direction of the parent WO₃ lattice and contain groups of six edge-sharing octahedra. Slabs of corner-sharing WO_6 octahedra (ReO₃ type), with a characteristic width equal to n, extend between the planes. The W atoms are all situated in a mirror plane perpendicular to the CS-planes.

Two additional members, $W_{25}O_{73}$ (4) and $W_{40}O_{118}$ (5), of the series have later been identified by X-ray methods. Both structures contain a puckered arrangement of the W atoms. Transmission electron mi-

croscopy observations of $W_{25}O_{73}$ crystals indicated some disorder in the CS-plane spacings. However, the average structure was found to be $W_{25}O_{73}$ (4).

Lately, electron microscopy observations of different samples of WO_{3-x} , $x \sim 0.1$, have shown that reduction of WO_3 to oxygen contents in the $0.07 \le x \le 0.12$ region introduces {103} CS-planes and yields structures corresponding to $W_{16}O_{46}$ - $W_{30}O_{88}$ (6-8). Most of the examined crystals were formed under nonequilibrium conditions, which resulted in disorder in the spacings and in the directions of the {103} CS-planes, i.e., frequent twinning.

The present study was primarily initiated by the observation that needle crystals of a bulk composition $WO_{\sim 2.90}$ formed by vapor transport gave Weissenberg photographs which showed similarities to both $W_{20}O_{58}$ and WO_3 . An investigation based upon Xray data and transmission electron microscopy observations was carried out in order to clarify the detailed structure of a proba-

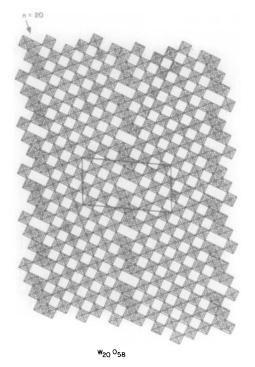


FIG. 1. Idealized representation of the monoclinic structure of $W_{20}O_{58}$ projected onto the *ac*-plane. The unit cell (of $W_{20}O_{58}$) is indicated. The number of octahedra in the diagonal row (arrow) between the *CS*-planes represents *n* in the formula W_nO_{3n-2} .

ble new member of the series W_nO_{3n-2} . Some preliminary data concerning this phase were presented by Magnéli (9).

Preparation

The following preparation method was originally planned as an attempt to prepare good-quality single crystals of $W_{20}O_{58}$. Amounts of WO_3 and WO_2 appropriate to give the gross composition $WO_{2.90}$ were carefully mixed and then heated in evacuated sealed silica tubes for 10 days in a moderate temperature gradient (~75°C). The sample ($WO_{2.90}$) was kept in the hotter part of the furnace, $T = 1075^{\circ}$ C, while the crystals examined in this study formed in the cooler part of the sample tube (1000°C). The temperatures were maintained for 3 days, and then lowered by 175°C over 3 days and again held fixed for 4 days (cooler end at 825°C). Finally, the sample was quenched to room temperature. The amount of transported material formed was too small for chemical analysis.

Optical microscopy showed the residue to consist of tiny dark-blue needles, while the transported part contained fairly large dark-blue needles of different lengths. The Guinier powder photograph of the residue indicated the phase $W_{20}O_{58}(3)$ and was not further considered. The Guinier photograph of the transported crystals indicated a phase mixture of {103} *CS*-structure and $WO_3(o-rh.)$.

Single-Crystal X-Ray Investigation

Several different transported crystals were examined by the Weissenberg technique. After a long exposure time a rotation photograph showed that the *b*-axis length was 7.56 Å, twice that of $W_{20}O_{58}(3)$, giving rise to weak extra layer lines. The Weissenberg photographs indicated that the reflection positions in the reciprocal lattice planes h0l, h2l, and h4l were practically identical and similar to those of $W_{20}O_{58}$. The positions of the reflections, all very weak, in the h1l and h3l reciprocal lattice planes were identical, and in addition these layer lines were somewhat similar to the weak layer lines of WO₃ (mon.) with l =odd. The weak reflections gave rise to a doubling of the a- and b-axes and hence a superstructure. The diffraction spots were mostly very streaked in the c-axis direction, indicating disorder in the structure. The unit cell dimensions of the subcell were found to be a = 12.07 Å, b = 3.78 Å, c =28.9 Å, $\beta = 98.6^{\circ}$. A Patterson projection based on data from the h0l reciprocal lattice plane (Fig. 2) could be interpreted in terms of a structure $W_{24}O_{70}$, homologous to that of $W_{20}O_{58}(3)$.

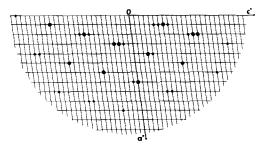


FIG. 2. The reciprocal lattice plane h0l (the planes h2l and h4l look essentially the same). Lattice points corresponding to observed reflections are marked with dots.

Electron Microscopy Investigation

Transported crystals were also examined by transmission electron microscopy using the lattice image technique described, for example, by lijima (10), and by Allpress and Sanders (11). The crystals were crushed under *n*-butanol in an agate mortar and deposited on a perforated carbon film supported by a copper grid. Then the crystal fragments were examined in a Siemens ELMISKOP 102 equipped with a double tilt-lift stage and operated at 125 kV. Only very thin crystal fragments extending across holes in the carbon film were examined. They were aligned with the electron



FIG. 3. Electron diffraction pattern taken of a transported crystal fragment with $n \sim 24$. The diffraction spots are somewhat streaked which indicates disorder.

beam parallel to the short crystal *b*-axis, so that the (*h*0*l*) section could be viewed on the screen. The size of the objective aperture used corresponded to 0.27 Å⁻¹.

Electron diffraction patterns recorded from some 25 crystal fragments showed all flakes to contain {103} CS-planes. The electron diffraction spots were also more or less streaked, indicating disorder in the flakes (Fig. 3). In a few cases the n value could not be exactly calculated because of severe streaking, and sometimes two sets of spots corresponding to two different nvalues were superimposed. The distribution of evaluated n values from 24 different crystal flakes is shown in Fig. 4. The dominating value is n = 24, suggesting a composition close to $W_{24}O_{70}$ ($WO_{2.917}$) of the transported crystal fragments being studied.

Lattice images of the same crystal fragments in most cases showed regions of fairly well-ordered CS-plane spacings, separated by wide slabs of apparently unreduced WO₃. Examples are given in Figs. 5a and b, which show the micrographs of two different crystal fragments. Figure 5a depicts a fairly well-ordered crystal fragment, while the one in Fig. 5b is much more disordered. The CS-plane spacings were carefully measured and the corresponding *n* values calculated. Figure 6a shows the distribution of CS-plane spacings over a region

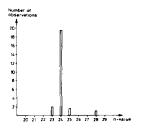


FIG. 4. The distribution of *n* values evaluated from 24 different crystal fragments. *n* corresponds to the spacing in the ordered structure of W_nO_{3n-2} . The dominating *n* value is n = 24. When the diffraction pattern indicated two different *n*-values a weight of $\frac{1}{2}$ was assigned to each.

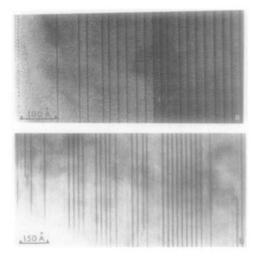


FIG. 5. Lattice images of two transported crystal fragments. (a) A fairly well-ordered crystal fragment with three large CS-plane spacings is shown. (b) Lattice image of transported crystal fragment WO~2.95 showing the CS-phase W24O70 intergrown with slabs of apparently unreduced WO3 (giving an overall composition WO_{~2.95}). Stopping and weak traces of CS-planes can be seen.

of \sim 1900 Å in the same crystal as in Fig. 5b. The variation in spacing over a group of CS-planes is in the range 23-37 Å, corresponding to n = 20-31. From the distribution of CS-plane spacings the composition

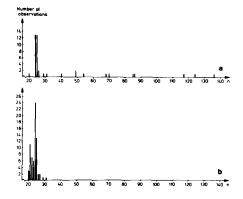


FIG. 6. (a) Distribution of CS-plane spacings evaluated from the flake shown in Fig. 5b. The x-axis represents the width of the CS-plane spacings, expressed by the corresponding n value, while the y-axis gives the frequency. (b) Distribution of CS-plane spacings evaluated from the same fragment as in Fig. 5b, but after introduction of hypothetic CS-planes.

of the crystal fragment was calculated to be ~WO_{2.95}.

More statistical evidence was obtained when the images of seven different crystal fragments were analyzed. The results are shown in Table I. The interplanar spacing varied within the range 21-38 Å over a group of CS-planes, corresponding to n =18-32, with a pronounced maximum at n =24. The widths of the large CS-free slabs

Hypothetic CS-Planes									
Diffraction pattern n	Variation in width over a group of CS-plane spacings		Average composition of the studied	Average composi- tion of the flake after introduction of hypothetic					
	Range n	Mode n	crystal fragments WO_x	CS-planes					
				WO _x	n				
24	18-32	25	2.941	2.917	24				
25	22-32	24, 25	2.935	2.920	25				
24	20-31	24, 25	2.949	2.917	24				
24	19-32	24, 25	2.949	2.917	24				
24	23-31	24	2.951	2.917	24				
25	19-29	25	2.938	2.913	23				
23	18-30	23	2.952	2.913	23				

TABLE I

Average Composition of Seven Crystal Fragments before and after Introduction of

were mostly in the region 50-160 Å. Some larger spacings have also been observed. The average composition WO_x of the crystal fragments studied seems to be in the region x = 2.93-2.95.

An observation frequently made is illustrated in Fig. 5b. At some places in the wide CS-free slabs, stopping CS-planes and weak contrast feature resembling diffuse shear planes can be seen. This observation initiated a careful examination of the wide WO_3 bands. It turned out that hypothetic CS-planes could be inserted in the wide WO_3 slabs in such a way that a uniform CSplane spacing was obtained. The results are shown in Table I. As an example, if such an insertion is made in Fig. 5b the histogram of Fig. 6a will turn into that of Fig. 6b. The CS-plane spacings will now be distributed over the region 23–37 Å, corresponding to n = 20-31, with a maximum at n = 24, giving the average composition $\sim WO_{2.917}$ of the flake. This agrees with the value n = 24obtained from the corresponding electron diffraction pattern.

Discussion

The results obtained from diffraction experiments, both the electron diffraction study (shown in Fig. 3) and the singlecrystal X-ray investigation, indicate that the dominating structure is $W_{24}O_{70}$; hence the composition $WO_{2.917}$ (apart from some disorder) of the examined crystal fragments. On the other hand, the results obtained from the lattice images show an entirely different composition of the fragments. Still, however, the crystal structure seems to be the *CS*-phase $W_{24}O_{70}$, intergrown with slabs of apparently unreduced WO_3 to give an overall composition in the region $WO_{2.93}$ - $WO_{2.96}$.

The $W_{24}O_{70}$ crystal structure is very similar to that of $W_{20}O_{58}$, shown in Fig. 1. The main difference is that the $W_{24}O_{70}$ slabs are

24 octahedra wide in the characteristic direction instead of 20 as in $W_{20}O_{58}$. Another difference between the two oxides concerns the positions of the tungsten atoms. In $W_{20}O_{58}$ all W atoms are located at the plane y = 0.5 (3) but in "W₂₄O₇₀," the W atoms are displaced from that plane. It was not possible to solve the displacement of W atoms from the center of the octahedra in detail from the X-ray data, but the observation of weak reflections in odd reciprocal lattice planes suggested an arrangement of the W atoms similar to that in WO_3 (mon. or o-rh.). In WO₃ (mon.) (12) there is a threedimensional displacement of the W atoms from the center of the octahedra, while in $WO_3(o-rh.)(13)$ the displacement is only in two directions. Both these types of displacement are shown in Fig. 7.

Earlier X-ray investigations of $\{103\} CS$ structures have shown that $W_{25}O_{73}$ and $W_{40}O_{118}$ have puckered arrangements of the W atoms (4, 5) whereas $W_{20}O_{58}$ has not. In $W_{25}O_{73}$, the displacement of the W atoms in the *b*-axis direction is least at the *CS*-plane and is largest in the middle of the slab (4).

As discussed above the crystals examined consisted of a $\{103\}$ CS-structure $-W_{24}O_{70}$ intergrown with slabs of unreduced WO₃. The fact that WO₃ is the substructure of the shear structure, is the reason why the X-ray investigation did not reveal the bands of CS-free tungsten trioxide. However, the weak reflections in the

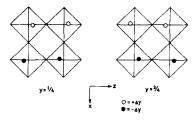


FIG. 7. Displacements (exaggerated) of the W atoms from the centers of the octahedra are shown for WO_3 (mon.). In the WO_3 (o-rh.) structure the displacements are essentially the same in the y- and z-direction but with no displacement in the x-direction.

odd reciprocal lattice layers, which cause the doubling of the crystal *b*-axis and hence a superstructure similar to that of WO₃ (mon. or o-rh.), may be caused largely by the displacements of the W atoms in the wide WO₃ slabs.

Another observation, which is important in the discussion of the type of displacement of the W atoms in different tungsten oxides, is the length of the corresponding unit cell b-axis. Magnéli et al. (15) pointed out that the length of the *b*-axis in the $(Mo, W)_n O_{3n-1}$ series decreases with increasing tungsten content, reflecting the formation of more regular WO_6 octahedra. From Table II, which shows the unit cell dimensions of different tungsten oxides, it can be seen that the oxides $W_{25}O_{73}$ and $W_{40}O_{118}$ have b-axes > 3.8 Å. These two oxides adopt puckered arrangements of the tungsten atoms. The crystals examined in this study have a *b*-axis which is about the same length as that in WO₃ (mon.) and WO₃ (orh.) and also very close to that of $W_{20}O_{58}$ (apart from the doubling). This fact probably indicates that the examined crystals do not have strongly one-dimensionally puckered arrangements of the W atoms such as those in $W_{25}O_{73}$ and $W_{40}O_{118}$.

According to earlier studies of the formation and growth of CS-planes in reduced WO₃ (16) some CS-planes in Fig. 8 can be interpreted as having grown into crystal during observation in the electron micro-

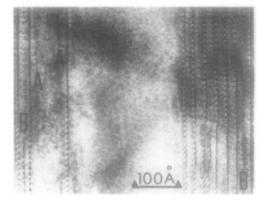


FIG. 8. Groups of fairly well-ordered CS-phase W_nO_{3n-2} slabs intergrown with slabs of apparently unreduced WO₃ can be seen. Weak traces of probably "old" CS-planes can be seen at A. Traces of CS-planes formed in the electron microscope can be seen at B.

scope. This in situ reduction which sometimes took place was due to the high vacuum in the electron microscope in combination with the heat from the electron beam (16). The new CS-planes were mostly observed to grow between existing planes, in the CS-region. If a new CS-plane grew in the WO_3 slab, the growth always took place at the edge close to existing CSplanes-never in the middle of the slab, as can be seen in Fig. 8. This observation probably indicates that the off-center displacement of W atoms decreases from a maximum in the wide WO_3 slab to a minimum at the CS-planes. It seems likely that the displacements of W atoms in the wide

UNIT CELL DIMENSIONS OF TUNGSTEN OXIDES								
	a (Å)	b (Å)	c (Å)	β	Reference			
W ₂₀ O ₅₈	12.05	3.767	23.59	94.72°	(3)			
$\sim W_{24}O_{70} + WO_3$	24.1	7.54	28.9	98.6°	This study			
W ₂₅ O ₇₃	11.93	3.82	59.72	98.3°	. (4)			
W ₄₀ O ₁₁₈	11.9	3.815	49.4	106.4°	(5)			
WO ₃ (mon.)	7.30	7.53	7.68	90.54°	(12)			
WO_3 (o-rh.)	7.341	7.57	7.754		(13)			
WO ₃ (tetr.)	5.25		3.91		(14)			

TABLE II Init Cell Dimensions of Tungsten Oxide

 WO_3 slab are larger than those in the CSregions. A large displacement of W atoms thus probably stabilizes the local composition of the apparently unreduced WO_3 domains.

The above observation also agrees with the postulation that the growth of new CSplanes is controlled by the elastic strain energy (17). Theoretical calculations on similar situations (18-20) have shown that this factor could be important in this sort of situation.

The observation of stopping CS-planes and weak traces of CS-planes in wide WO₃ slabs may indicate that the sample has been oxidized in the course of the preparation, after the formation of a shear structure. As can be seen from the last column in Table I, the introduction of hypothetic CS-planes in wide WO₃ slabs reduced the composition of the studied crystal flakes to within the region WO_{2.913}-WO_{2.926}, with an average composition of the sample at WO_{2.917} (n =24). This value of the composition agrees too well with results obtained from the Xray study and the electron diffraction pattern to be pure coincidence.

Another interesting fact is that the average oxygen content of the crystal fragments studied ($WO_{2.93}$ - $WO_{2.96}$) is higher than expected for a material containing {103} CS-planes. In previous electron microscopy observations of slightly reduced tungsten trioxide {103} CS-planes have only been observed for compositions up to $\sim WO_{2.93}$ (6-8). Above $\sim WO_{2.93}$ {102} CS-planes have been found (7, 21, 22).

The observations suggested the following hypothesis for the formation of the wide *CS*-plane spacings. The transported crystals were originally formed with an overall composition $W_n O_{3n-2}$, $n \sim 24$ (in accordance with the electron diffraction pattern and the X-ray observations). Decreasing temperature during the experiment caused a change of the equilibrium in the sample tube toward more oxidizing conditions, which resulted in elimination of some CSplanes. The oxidation of the CS-planes did not take place uniformly through the examined crystal fragments, but was concentrated to some parts of the crystals where it resulted in a locally complete reoxidation of the flake.

A systematic variation of the CS-spacings within the " $W_{24}O_{70}$ " regions, similar to what has been reported for slightly reduced rutile (23), has not been observed. This is consistent with the hypothesis that an oxidation with elimination of shear planes in wide areas has taken place.

It is interesting to note that the wide slabs of unreduced WO₃ have been found in several samples of vapor-grown crystals containing $\{103\}$ CS-planes, but never in the bulk material.

From the results presented here, concerning transported crystals of slightly reduced tungsten trioxide, it can be seen that the composition is not the only relevant factor influencing the shear type. The formation of wide CS-plane spacings which probably takes place by an oxidation process during the preparation is still not solved in detail, but further experiments are under way which hopefully will clarify the oxidation mechanism. The investigation illustrates also the complementary applicability of the X-ray and electron microscopy techniques. The X-ray study gave detailed information about the idealized atomic arrangement of the W24O70 phase. The presence of WO_3 intergrown with the $W_{24}O_{70}$ phase could only be found by means of the lattice image investigation.

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